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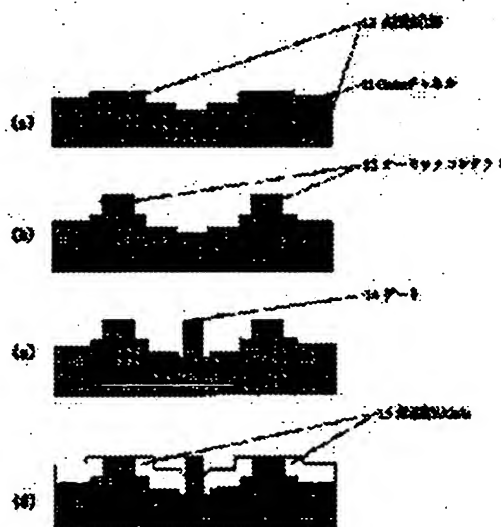
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## (54) MANUFACTURE OF FIELD-EFFECT TRANSISTOR

### (57)Abstract:

**PURPOSE:** To obtain easily a field-effect transistor, which has a high reliability, high breakdown strength, a high output and a high efficiency and moreover, is not subjected to effect of a surface defect level, by a method wherein after a gate electrode is provided on a channel subjected to recess etching, non-doped GaAs layer, an AlGaAs layer or an InAlAs layer is formed.

**CONSTITUTION:** Boron is ion-implanted in parts other than a channel to form layers 12 having high resistance and after an interelement isolation is performed, a GaAs channel 11 is subjected to mesa etching to a desired form in two stages. An oxide film is formed on the whole surface, a mask for ohmic contact use is applied, the oxide film on the parts of source and drain electrode is opened and after ohmic contacts 13 are formed, a heat treatment is performed. The oxide film on the part of a gate electrode is opened and a gate 14 is formed. Non-doped AlGaAs layers 15 are formed by an atomic layer epitaxial growth method using an organic metal. Thereby, a field-effect transistor having a high reliability, a high output, a high efficiency and a high breakdown strength is obtained.



## LEGAL STATUS

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